

**SH193 Hall Effect Latch with Built-in Pull-up Resistor**

SH193 is an ultra-high sensitivity Hall effect latch designed in advanced DMOS technology. The following are integrated on a single silicon chip: voltage regulator, ESD protection, Hall voltage generator, chopper stabilized small-signal amplifier, Schmitt trigger, open-drain output and built-in pull-up resistor. Since the pull-up resistor is built, external pull-up resistor is not required. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization.

**Features**

- Ultra-high sensitivity (1.5mT typ.)
- Built-in pull-up resistor (10kΩ)
- Stable temperature characteristics
- Good ESD protection (HBM4kV min.)

**Typical Applications**

- High temperature fan motor
- 3 phase BLDC motor
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting

**Order Information**

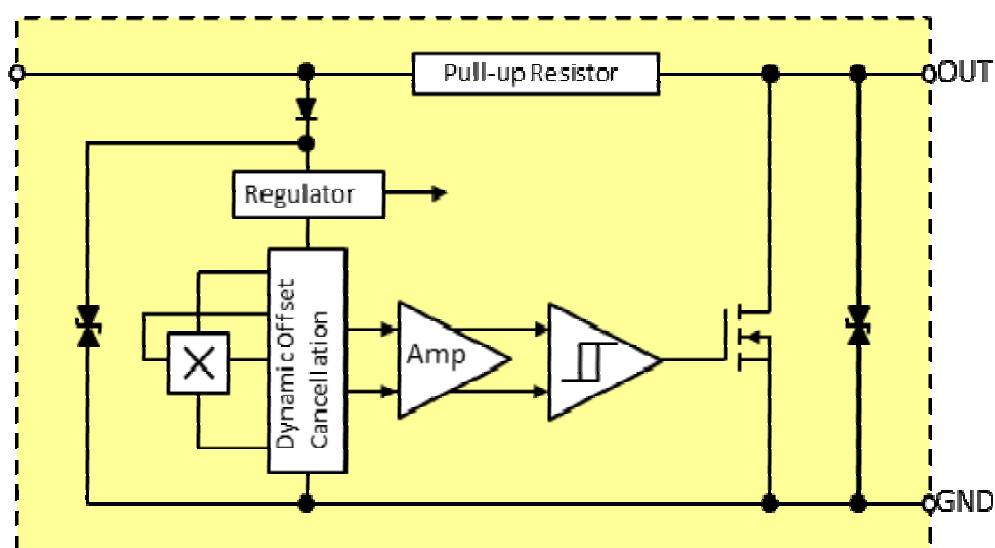
Order No.	Part No.	Temperature	Package	—	Packing
SH193KUA	SH193	K	UA		
SH193KSO-TR	SH193	K	SO	—	TR

Legend:

Temperature Code: K (-40°C~125°C)

Package Code: UA (TO92S), SO (SOT23)

Packing Code: Brank (Balk, 500pcs/Bag), TR (Tape & Reel, 3,000pcs/Reel)

**Functional Block Diagram**


**Absolute Maximum Ratings** ( $T_A=25^{\circ}\text{C}$ )

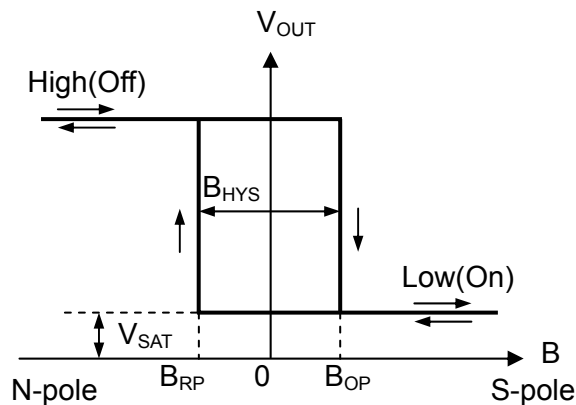
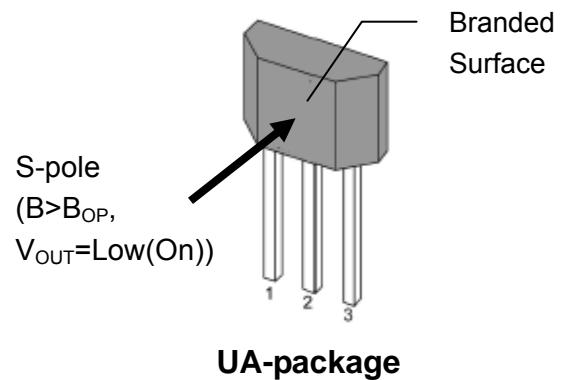
Parameter	Symbol	Value		Unit
		Min	Max	
Supply Voltage	$V_{DD}$	-0.3	18	V
Output Voltage	$V_{OUT}$	-0.3	18	V
Output Current	$I_{SINK}$	-	13	mA
Operating Temperature Range (K)	$T_A$	-40	125	$^{\circ}\text{C}$
Storage Temperature Range	$T_S$	-65	150	$^{\circ}\text{C}$
Maximum Junction Temperature	$T_J$		150	$^{\circ}\text{C}$
Power Dissipation (UA/SO)	$P_D$		606/230	mW

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$ ,  $V_{DD}=12\text{V}$ )

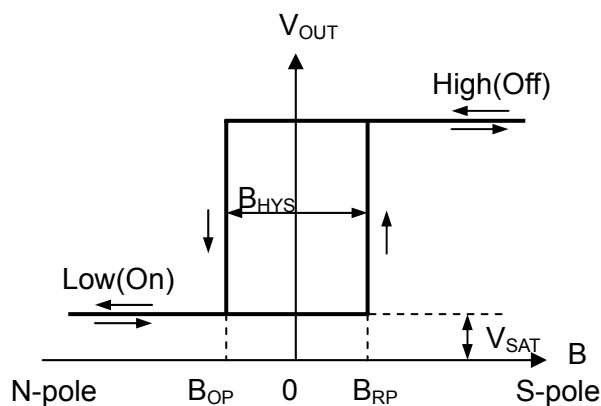
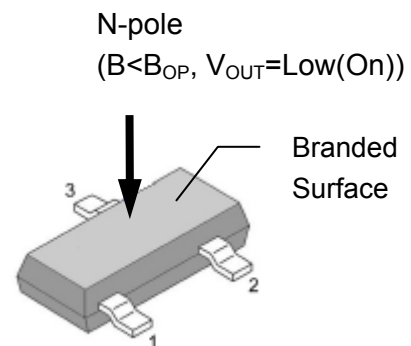
Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Supply Voltage		$V_{DD}$	2.5	-	16	V
Consumption Current	$V_{OUT}=\text{High}$	$I_{DD}$	-	-	5	mA
Output Saturation Voltage	$V_{OUT}=\text{Low}$	$V_{SAT}$	-	-	0.4	V
Output Leakage Current	$V_{OUT}=12\text{V}(\text{High})$	$I_{LEAK}$	-	-	10	$\mu\text{A}$
Output Rise time	$R_L=1.1\text{k}\Omega$ , $C_L=20\text{pF}$	$t_R$	-	0.04	0.45	$\mu\text{s}$
Output Fall time	$R_L=820\Omega$ , $C_L=20\text{pF}$	$t_F$	-	0.18	0.45	$\mu\text{s}$
Electro-Static Discharge	HBM		4	-	-	kV
Built-in Pull-up Resistor		$R_{PU}$		10		k $\Omega$

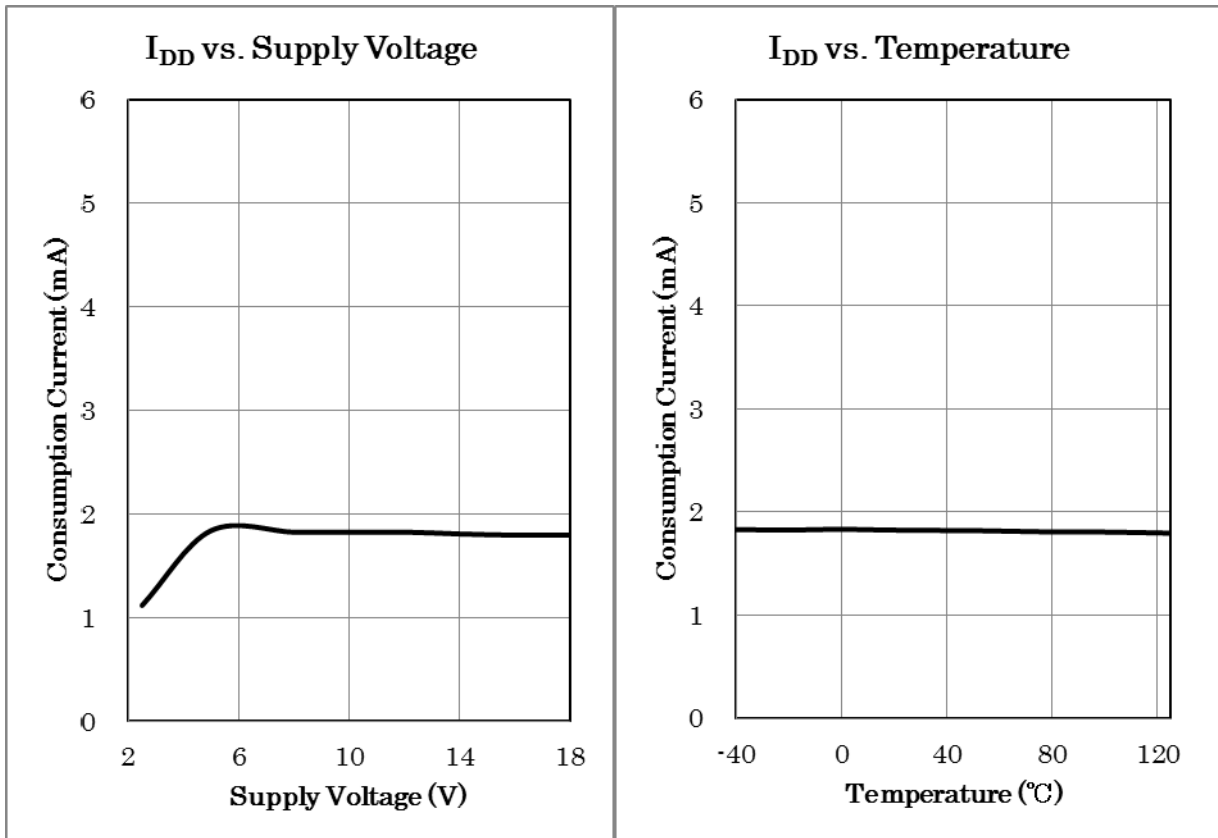
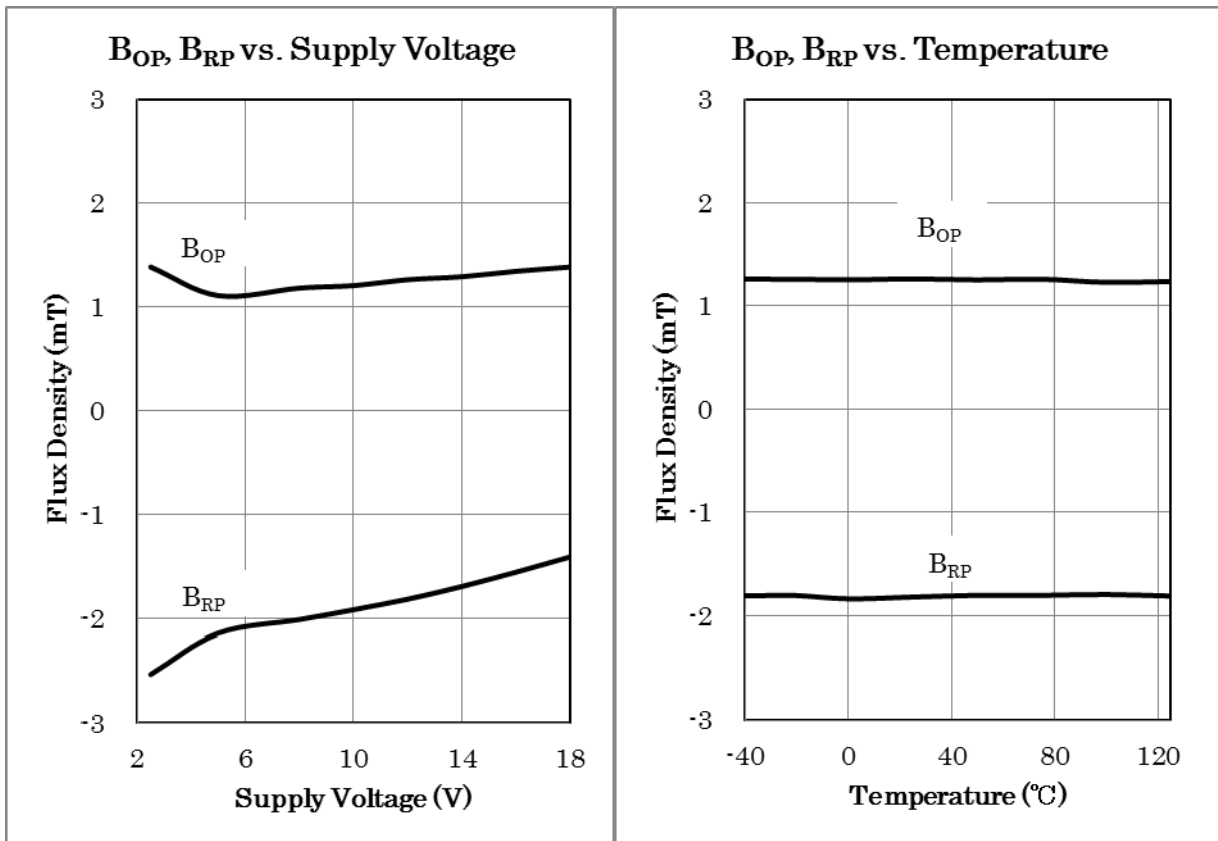
**UA-package Magnetic Characteristics** ( $T_A=25^\circ\text{C}$ ,  $V_{DD}=12\text{V}$ )

Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Operate Point	S pole to branded side	$B_{OP}$	0.5	-	2.5	mT
Release Point	N pole to branded side	$B_{RP}$	-2.5	-	-0.5	mT
Hysteresis		$B_{HYS}$	-	3	-	mT


**Switching Characteristics**

**UA-package**
**SO-package Magnetic Characteristics** ( $T_A=25^\circ\text{C}$ ,  $V_{DD}=12\text{V}$ )

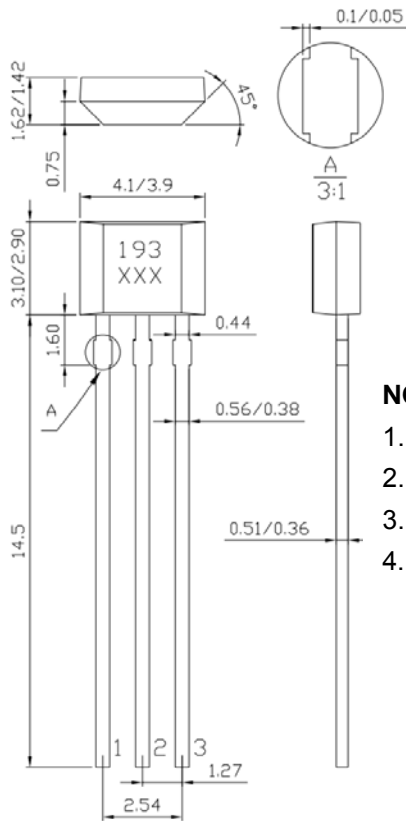
Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Operate Point	N pole to branded side	$B_{OP}$	-2.5	-	-0.5	mT
Release Point	S pole to branded side	$B_{RP}$	0.5	-	2.5	mT
Hysteresis		$B_{HYS}$	-	3	-	mT


**Switching Characteristics**

**SO-package**

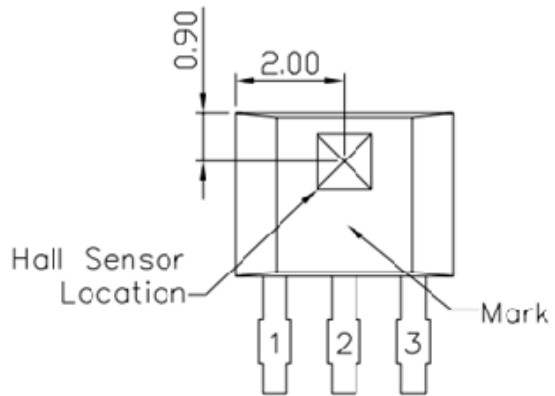
**Performance Graphs**


Sensor Location, Package Dimension and Marking

UA-package: T092S



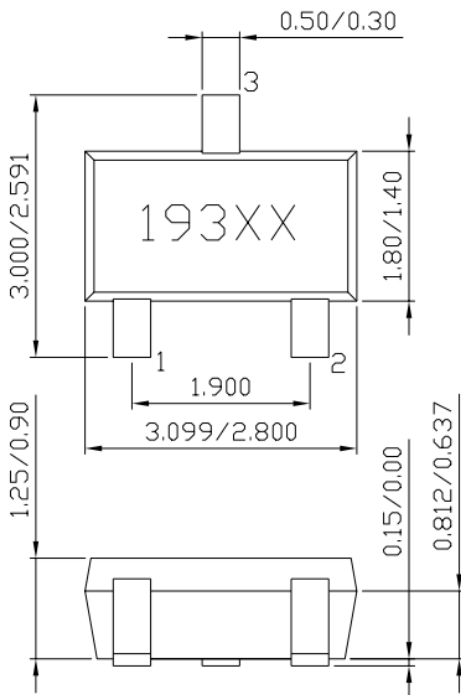
Hall sensor location



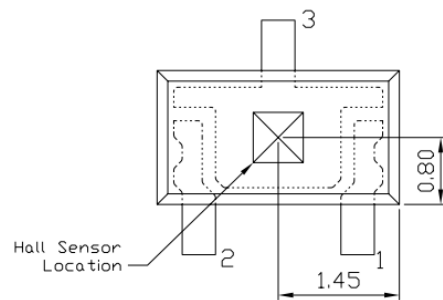
NOTES:

1. Controlling dimension: mm;
2. Leads must be free of flash and plating voids
3. Do not bend leads within 1 mm of lead to package interface
4. PINOUT:  
Pin 1  $V_{DD}$   
Pin 2 GND  
Pin 3 Output

SO-package: SOT23  
(Upper View)



Hall sensor location  
(Bottom View)



NOTES:

1. PINOUT:  
Pin 1  $V_{DD}$   
Pin 2 Output  
Pin 3 GND
2. Controlling dimension: mm;
3. Lead thickness after solder plating will be 0.254mm maximum.